



a anode formed on a conductive substrate and said anode comprising a lithium layer including therein either one of a metallic lithium and an alloy thereof,

wherein said lithium layer further contains at least

5 one type of metal fluoride substance.

7. A lithium secondary cell according to claim 6, wherein said lithium layer is formed by vacuum film growth method.

10 8. A lithium secondary cell according to claim 6, wherein an amount of said metal fluoride substance within said lithium layer is 1 to 50at%.

15 9. A lithium secondary cell according to claim 1, comprising a hydrophobic layer containing at least one type of a hydrocarbon or ester, including therein one in which carbon is partially replaced by silicon or one in which hydrogen is partially or totally replaced by fluorine on a surface of said anode.

20 10. A lithium secondary cell according to claim 6, comprising a hydrophobic layer containing at least one type of a hydrocarbon or ester, including therein one in which carbon is partially replaced by silicon or one in which hydrogen is partially or totally replaced by fluorine on a surface of said anode.

25 11. A lithium secondary cell according to claim 9, wherein said metal fluoride substance layer is disposed below said hydrophobic substance layer.

12. A lithium secondary cell according to claim 10, wherein said metal fluoride substance layer is disposed below said hydrophobic substance layer.

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13. A lithium secondary cell according to claim 2,  
comprising a hydrophobic layer containing at least one  
type of a hydrocarbon or ester, including one in which  
carbon is partially replaced by silicon and one in which  
5 hydrogen is partially or totally replaced by fluorine  
formed under said metal fluoride substance layer.

14. A lithium secondary cell, comprising:

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10 a anode formed on a conductive substrate and said  
anode comprising a lithium layer including therein either  
one of a metallic lithium and an alloy thereof, said  
anode further comprising a metal fluoride substance layer  
comprising at least one type metal fluoride,  
said anode comprising a hydrophobic substance layer which  
comprising at least one type of a hydrocarbon or ester,  
15 including one in which carbon is partially replaced by  
silicon or one in which hydrogen is partially or totally  
replaced by fluorine and metal fluoride substance layer  
which comprising at least one type of metal fluoride  
substance,

20 wherein a surface of said anode comprising said  
hydrophobic substance layer or said metal fluoride  
substance layer.

15. A lithium secondary cell according to claim 12,  
wherein:

25 said metal fluoride substance layer is disposed on a  
surface of said anode,

said hydrophobic substance layer is disposed  
therebelow, and

said lithium layer is disposed below said hydrophobic substance layer.

16. A lithium secondary cell according to claim 12,  
wherein:

5        said hydrophobic substance layer is disposed on a  
      surface of said anode,

said metal fluoride substance layer is disposed below said hydrophobic substance layer, and

said lithium layer is disposed below said metal  
10 fluoride substance layer.

17. A lithium secondary cell according to claim 12, wherein said lithium layer and said metal fluoride substance layer are formed by vacuum film growth method.

18. A lithium secondary cell according to claim 13,  
15 wherein said lithium layer and said metal fluoride  
substance layer are formed by vacuum film growth method.

19. A lithium secondary cell according to claim 14, wherein said lithium layer and said metal fluoride substance layer are formed by vacuum film growth method.

20 20. A lithium secondary cell according claim 1, wherein  
said metal fluoride substance comprises at least one  
selected from a group consisting lithium fluoride,  
magnesium fluoride, silver fluoride, aluminum fluoride,  
and calcium fluoride.

25 21. A lithium secondary cell according to claim 6,  
wherein said hydrophobic substance layer comprising a  
carboxylic acid ester, including one in which carbon is  
partially replaced with silicon or one in which hydrogen  
is partially or totally replaced with fluorine.

22. A lithium secondary cell according to claim 6,  
wherein said hydrophobic substance layer comprising at  
least one of a phthalic acid ester or benzoic ester,  
including one including one in which carbon is partially  
5 replaced with silicon or one in which hydrogen is  
partially or totally replaced with fluorine.

23. A lithium secondary cell according to claim 9,  
wherein said hydrophobic substance layer comprises at  
least substance selected from a group consisting dioctyl  
10 phthalate, cetyl naphthalene and neroli oil.

24. A method for manufacturing a lithium secondary cell,  
said method comprising a step of forming lithium layers  
comprising a lithium layer including therein a metallic  
lithium or an alloy thereof used for said anode and a  
15 metal fluoride substance layer comprising at least one  
type of metal fluoride substance by vacuum film growth  
method.

25. A method for manufacturing a lithium secondary cell  
according to claim 20, whereby a lithium secondary cell  
20 according to claim 1 is manufactured.

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